Supplementary Information

High-pressure structural phase transition and metallization in Ga₂S₃ under non-hydrostatic and hydrostatic conditions up to 36.4 GPa

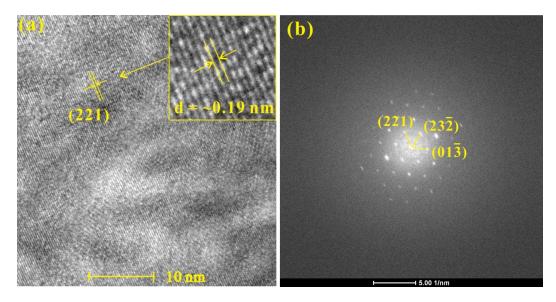
Linfei Yang,^{a‡} Jianjun Jiang,^{ba‡} Lidong Dai,^{*ba} Haiying Hu,^{*ba} Meiling Hong,^{ac}

Xinyu Zhang,^{ac} Heping Li^a and Pengfei Liu^d

 ^a Key Laboratory of High-Temperature and High-Pressure Study of the Earth's Interior, Institute of Geochemistry, Chinese Academy of Sciences, Guiyang, Guizhou 550081, China
^b Shandong Provincial Key Laboratory of Water and Soil Conservation and Environmental Protection, College of Resources and Environment Sciences, Linyi University, Linyi 276000, China
^c University of Chinese Academy of Sciences, Beijing 100049, China
^d State Key Laboratory of Structural Chemistry, Fujian Institute of Research on the Structure of Matter, Chinese Academy of Sciences, Fuzhou, Fujian 350002, China

*Corresponding author. Email address: dailidong@vip.gyig.ac.cn,

huhaiying@mail.gyig.ac.cn.



Supplementary Figures

Fig. S1 (a) HRTEM image for the initial sample at ambient conditions. (b) The corresponding FFT diagram of the initial sample.

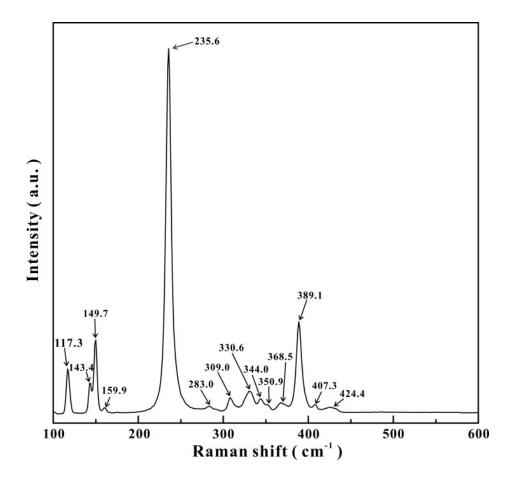


Fig. S2 The Raman spectra of Ga_2S_3 at ambient conditions collected in the region from 100 cm⁻¹ to 600 cm⁻¹.

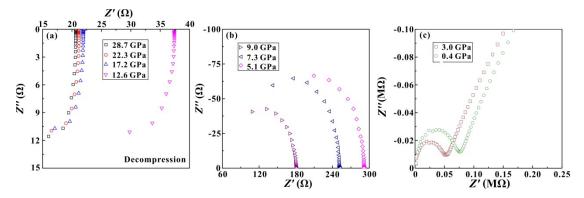


Fig. S3 (a)–(c) The impedance spectra of Ga₂S₃ at different pressures during the process of decompression.